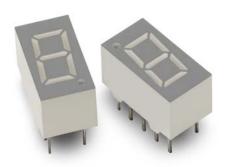
## HDSP-H3x1/H3x3

# 0.36" Single Digit PCB Based LED Display



## **Data Sheet**



## **Description**

The HDSP-H3x1/H3x3 is a 0.36 inch high, single-digit display series. These halogenated devices utilize AllnGaP red, orange, green and deep red chips. This device is halogenated.

All devices are categorized for luminous intensity. The orange and green devices are categorized for color. Use of similar device categories yields a uniform display.

#### **Features**

- High reliability
- Excellent characters appearance
- Available in CA and CC
- RoHS Compliant
- Gray top surface with white diffused segments.

**Table 1 Ordering Information** 

Red	Green	Orange	Deep Red	Description
HDSP-H3E1	HDSP-H3G1	HDSP-H3L1	HDSP-H3A1	Common Anode, Right Hand Decimal
HDSP-H3E3	HDSP-H3G3	HDSP-H3L3	HDSP-H3A3	Common Cathode, Right Hand Decimal

**Figure 1 Package Dimension** 

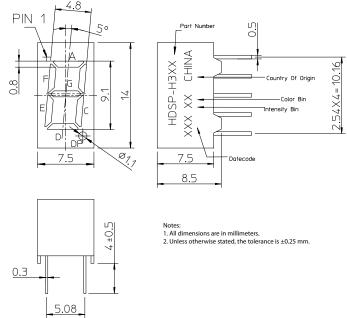


Figure 2 Circuit Diagram

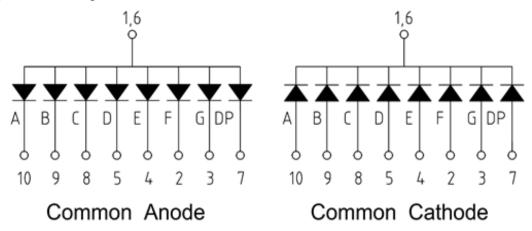


Table 2 Absolute Maximum Ratings at T<sub>A</sub> = 25°C

Parameter	Symbol	Red/Orange/Green/Deep Red	Units
Power Dissipation per segment or Dot Point (DP)	$P_{D}$	52	mW
Continuous Forward Current per segment	I <sub>F</sub>	20	mA
Peak Forward Current per segment (1/10 Duty Cycle, 0.1m sec pulse width		100	mA
Derating Linearly from 25°C per segment		0.21	mA/°C
Reverse Voltage per segment or DP	V <sub>R</sub>	Not designed for reverse biasing	
Operating Temperature	T <sub>O</sub>	-40 to 85	°C
Storage Temperature	T <sub>S</sub>	-40 to 85	°C
Wave solder Condition 1.6mm below body		260°C peak for 3 secs max	

Table 3 Red Electrical/Optical Characteristics at  $T_A = 25^{\circ}C$ 

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Average Luminous Intensity (Digit Average)	I <sub>v</sub>	_	15	_	mcd	I <sub>F</sub> = 10 mA
Peak Wavelength	λρ	_	634	_	nm	I <sub>F</sub> = 20 mA
Dominant Wavelength	λ <sub>d</sub>	_	625	_	nm	I <sub>F</sub> = 20 mA
Forward Voltage per segment / DP	V <sub>F</sub>	_	2.0	2.6	V	I <sub>F</sub> = 20 mA
Reverse Current per segment / DP <sup>a</sup>	I <sub>R</sub>	_	_	100	μΑ	V <sub>R</sub> = 5 V
Luminous Intensity Matching Ratio (Segment to Segment)	I <sub>v-M</sub>	_	2:1	_	_	I <sub>F</sub> = 10 mA

a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

Table 4 Green Electrical/Optical Characteristics at  $T_A = 25^{\circ}C$ 

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Average Luminous Intensity (Digit Average)	I <sub>v</sub>	_	5	_	mcd	$I_F = 10 \text{ mA}$
Peak Wavelength	λ <sub>p</sub>	_	570	_	nm	I <sub>F</sub> = 20 mA
Dominant Wavelength	$\lambda_{d}$	_	571	_	nm	I <sub>F</sub> = 20 mA
Forward Voltage per segment / DP	V <sub>F</sub>	_	2.0	2.6	V	I <sub>F</sub> = 20 mA
Reverse Current per segment / DP <sup>a</sup>	I <sub>R</sub>	_	_	100	μΑ	V <sub>R</sub> = 5 V
Luminous Intensity Matching Ratio (Segment to Segment)	I <sub>v-M</sub>	_	2:1	_	_	I <sub>F</sub> = 10 mA

a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

Table 5 Orange Electrical/Optical Characteristics at  $T_A = 25^{\circ}C$ 

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Average Luminous Intensity (Digit Average)	I <sub>v</sub>	_	13	_	mcd	$I_F = 10 \text{ mA}$
Peak Wavelength	λ <sub>p</sub>	_	610	_	nm	I <sub>F</sub> = 20 mA
Dominant Wavelength	$\lambda_{d}$	_	605	_	nm	I <sub>F</sub> = 20 mA
Forward Voltage per segment / DP	V <sub>F</sub>	_	2.0	2.6	V	I <sub>F</sub> = 20 mA
Reverse Current per segment / DP <sup>a</sup>	I <sub>R</sub>	_	_	100	μΑ	V <sub>R</sub> = 5 V
Luminous Intensity Matching Ratio (Segment to Segment)	I <sub>v-M</sub>	_	2:1	_	_	I <sub>F</sub> = 10 mA

a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

#### Table 6 Deep Red Electrical/Optical Characteristics at $T_A = 25^{\circ}C$

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Average Luminous Intensity (Digit Average)	I <sub>v</sub>	_	12	_	mcd	$I_F = 10 \text{ mA}$
Peak Wavelength	$\lambda_{p}$	_	644		nm	I <sub>F</sub> = 20 mA
Dominant Wavelength	$\lambda_{d}$	_	635		nm	I <sub>F</sub> = 20 mA
Forward Voltage per segment / DP	V <sub>F</sub>	_	2.0	2.6	V	I <sub>F</sub> = 20 mA
Reverse Current per segment / DPa	I <sub>R</sub>	_	_	100	μΑ	5 V
Luminous Intensity Matching Ratio (Segment to Segment)	I <sub>v-M</sub>	_	2:1	_	_	I <sub>F</sub> = 10 mA

a. Indicates production go-no-go test only. Long term reverse biasing is not recommended.

#### Red

Figure 3 Relative Luminous Intensity Vs Forward Current

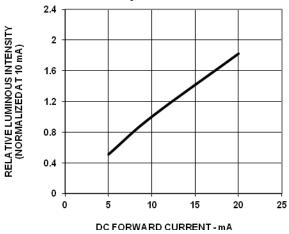


Figure 5 Relative Luminous Intensity Vs Wavelength

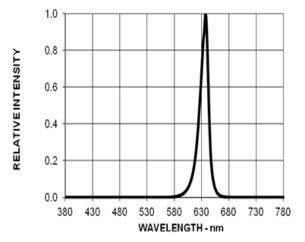
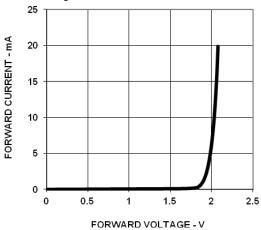


Figure 4 Forward Voltage Vs Current



#### Green

Figure 6 Relative Luminous Intensity Vs Forward Current

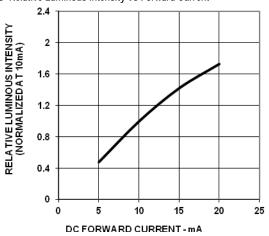


Figure 8 Relative Luminous Intensity Vs Wavelength

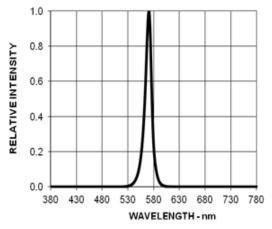
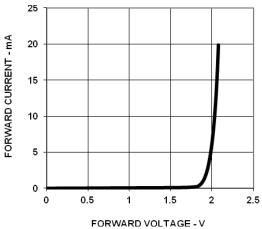


Figure 7 Forward Voltage Vs Current



## **Orange**

Figure 9 Relative Luminous Intensity Vs Forward Current

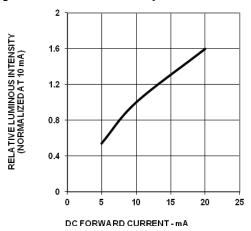


Figure 11 Relative Luminous Intensity Vs Wavelength

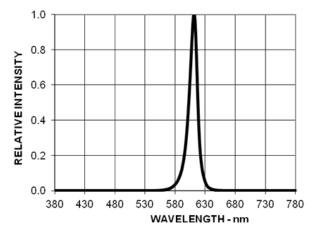
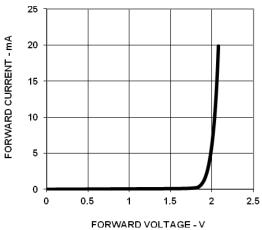


Figure 10 Forward Voltage Vs Current



## **Deep Red**

Figure 12 Relative Luminous Intensity Vs Forward Current

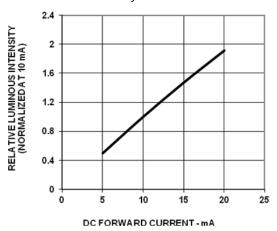


Figure 14 Relative Luminous Intensity Vs Wavelength

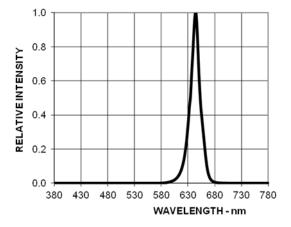
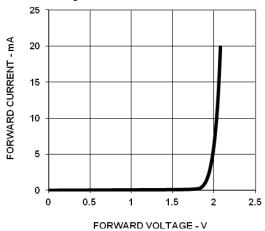
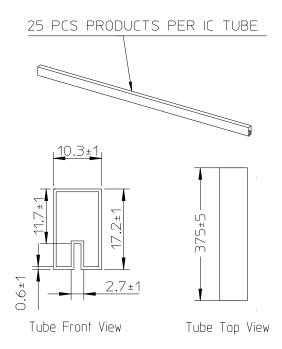


Figure 13 Forward Voltage Vs Current



#### **Packing Tube Specifications**



#### Reference

For further information on soldering LEDs, please refer to Avago Technologies Application Note 1027.

For product information and a complete list of distributors, please go to our web site: www.avagotech.com



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